

Data Sheet

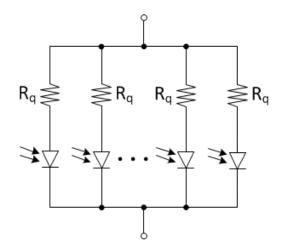
AFBR-S4N44C013 NUV-HD Silicon Photo Multiplier



Description

The Broadcom[®] AFBR-S4N44C013 is a silicon photo multiplier (SiPM) used for ultra-sensitive precision measurement of single photons. The active area is 3.72 x 3.72 mm². High packing density of the single chips is achieved using trough-silicon-via (TSV) technology. Larger areas can be covered by tiling multiple AFBR-S4N44C013 arrays almost without any edge losses. The passivation layer is made by a glass highly transparent down to UV wavelengths, resulting in a broad response in the visible light spectrum with high sensitivity towards blue- and near-UV region of the light spectrum. The SiPM is best suited for the detection of low-level pulsed light sources, especially for detection of Cherenkov- or scintillation light from the most common organic (plastic) and inorganic scintillator materials (for example, LSO, LYSO, BGO, Nal, Csl, BaF, LaBr). This product is lead free and compliant with RoHS and REACH.

Figure 1: AFBR-S4N44C013 Block Diagram



Features

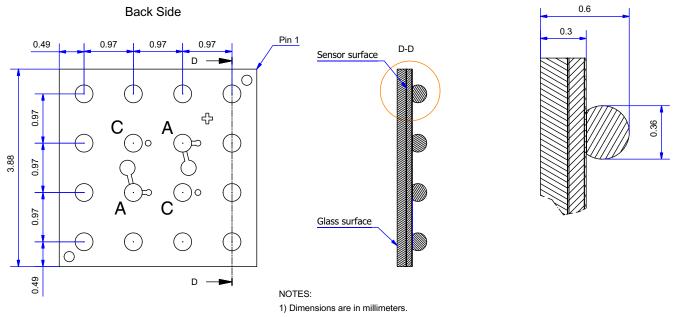
- High PDE of more than 55% at 420 nm
- High fill factors
- Excellent SPTR and CRT
- Excellent uniformity of break down voltage, 180 mV (3 sigma)
- Excellent uniformity of gain
- With TSV technology (4-side tilable)
- Size 3.88 x 3.88 mm²
- Cell pitch 30 x 30 µm²
- Highly transparent glass protection layer
- Operating temperature range from –20°C to +50°C
- RoHS and REACH compliant

Applications

- X-ray and gamma ray detection
- Gamma ray spectroscopy
- Safety and security
- Nuclear medicine
- Positron emission tomography
- Life sciences
- Flow cytometry
- Fluorescence luminescence measurements
- Time correlated single photon counting
- High energy physics
- Astrophysics

Pad Layout and Soldering Ball Geometry

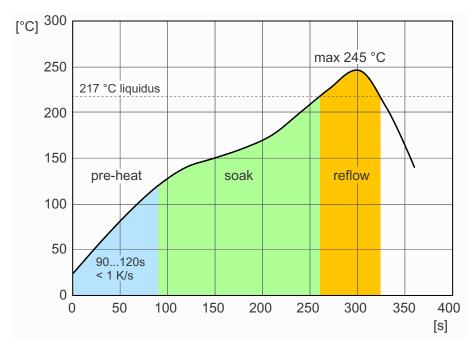
Figure 2: Bottom View (Left) and Cross Sections (Right)



2) Nominal values rounded to two decimal places - Suppression of following zeros.3) A is anode, C is cathode.

Reflow Soldering Diagram

Figure 3: Recommended Reflow Soldering Profile



Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause damage to the devices. Limits apply to each parameter in isolation. Absolute maximum ratings are those values beyond which damage to the device may occur if these limits are exceeded for other than a short period of time.

Parameter	Symbol	Min	Max	Unit
Storage Temperature	T _{STG}	-20	+60	°C
Operating Temperature ^a	T _A	-20	+50	°C
Soldering Temperature ^{b,c}	T _{SOLD}	_	245	°C
Lead Soldering Time ^{b,c}	t _{SOLD}	_	60	S
Electrostatic Discharge Voltage Capability HBM	ESD _{HBM}	—	2	kV
Electrostatic Discharge Voltage Capability CDM	ESD _{CDM}	_	500	V
Operating Over Voltage	V _{OV}	_	12	V

a. Biased at constant voltage = 7V above breakdown.

b. The AFBR-S4N44C013 is reflow-solderable according to solder diagram as shown in figure 3.

c. According to JEDEC J-STD-020D, the moisture sensitivity classification is MSL3.

Device Specification

Features measured at 20°C unless otherwise specified.

Geometric Features

Parameter	Symbol	Value	Unit
Device Area	DA	3.88 x 3.88	mm²
Active Area	AA	3.72 x 3.72	mm²
Micro Cell Pitch	L _{cell}	30	μm
Number of Micro Cells	N _{cells}	15060	—
Micro Cell Fill Factor	FF	76	%

Optical and Electrical Features

Two recommended working points: Typical for general purpose applications and Performance for best timing performance.

Parameter	Symbol	Min	Typ. ^a	Max	Perf. ^a	Unit	Reference Plots
Spectral Range	λ	300		900		nm	
Peak Sensitivity Wavelength	λ _{PK}	_	420	_		nm	Figure 4
Photo Detection Efficiency ^b	PDE	_	43	_	54	%	Figure 5
Dark Current	I _D	_	0.4		2.5	μA	Figure 6
Dark Count Rate ^c	DCR	_	1.1	_	2.5	Mcps	Figure 7, Figure 10
Dark Count Rate Per Unit Area	DCR _{mm²}	_	76	_	180	kcps/mm ²	
Gain	G	_	1.6	_	3.1	x10 ⁶	Figure 8, Figure 11
Optical Crosstalk	P _{Xtalk}	_	9	—	27	%	Figure 9, Figure 12
After Pulsing Probability	P _{AP}	_	<1	_	1	%	Figure 9, Figure 12
Recharge Time Constant ^d	T _{fall}	—	55	_	50	ns	Figure 13
Breakdown Voltage	V _{BD}	_	26.8	_		V	Figure 6
Overvoltage	V _{OV}		3.0	_	6.5	V	
Nominal Terminal Capacitance ^e	CT	_	990	_	760	pF	
Temperature Coefficient of Breakdown Voltage	$\Delta V_{BR} / \Delta T$	_	26	-	—	mV/K	
Temperature Coefficient of Gain	$\Delta G / \Delta T$	—	1.2	_	1.0	x10 ⁴ /K	

a. Typical values are measured at 3V above breakdown; performance at 6.5V above breakdown.

b. Measured at peak sensitivity-wavelength. Measurement does not include correlated noise, such as after-pulsing or optical crosstalk.

c. Measured at 0.5 p.e. amplitude. Measurement does not include delayed correlated events.

d. Measured on 1 x 1 mm^2 devices with an input impedance of 20 Ω .

e. Measured using input sine wave with f = 200 kHz and V_{in} = 500 mV.

Reference Plots

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Features measured at 20°C unless otherwise specified.

Figure 4: Spectral Sensitivity

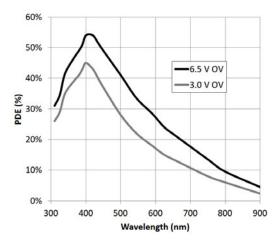


Figure 5: PDE at Peak λ vs OV

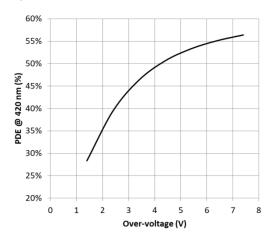


Figure 6: Typical Reverse IV Curve

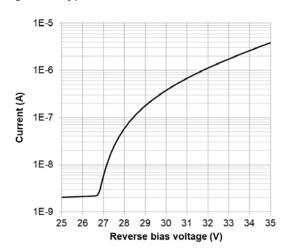


Figure 7: Dark Count Rate vs OV

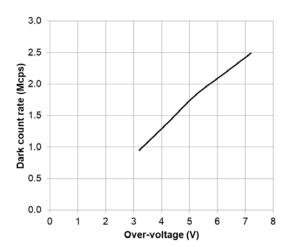


Figure 8: Gain vs OV

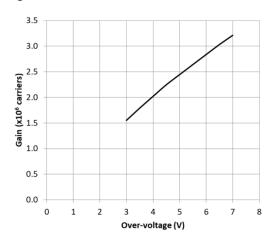
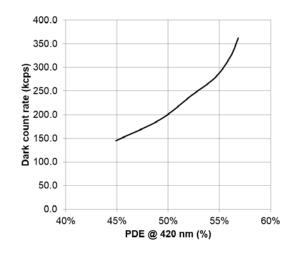


Figure 10: Dark Count Rate vs PDE at Peak λ





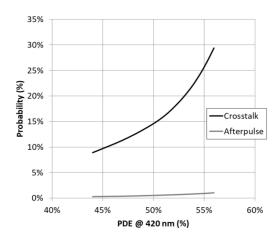


Figure 9: Correlated Noise vs OV

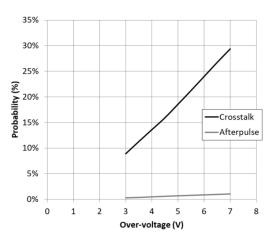


Figure 11: Gain vs PDE at Peak λ

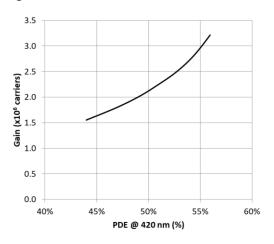
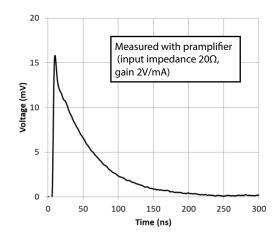


Figure 13: Example Signal Measured at 3V OV



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